TOSHIBA TLP666JF

## TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

## **TLP666JF**

OFFICE MACHINE HOUSEHOLD USE EQUIPMENT TRIAC DRIVER **SOLID STATE RELAY** 

The TOSHIBA TLP666JF consists of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.

All parameters are tested to the specification of TLP666J. (both condition and limits)

Peak Off-State Voltage: 600V (Min.) Trigger LED Current 10mA (Max.)

On-State Current 100mA (Max.)

**UL** Recognized UL1577, File No. E67349

Isolation Voltage  $5000V_{rms}$  (Min.)

Option (D4) type

VDE Approved DIN VDE0884/08.87, Certificate No. 68383

Maximum Operating Insulation Voltage: 630VpK

Highest Permissible Over Voltage 6000VPK

(Note 1) When a VDE0884 approved type is needed, please designate the "Option (D4)"

Structural Parameter

Creepage Distance : 8.0mm (Min.) Clearance : 8.0mm (Min.) Insulation Thickness : 0.5mm (Min.)

Conforming Safety Standards:

DIN 57 804/VDE0804/1.83 DIN IEC65/VDE0860/8.81 DIN IEC380/VDE0806/8.81

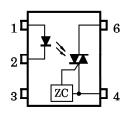
DIN IEC435/VDE0805/Draft Nov. 84 DIN IEC601T1/VDE0750T1/5.82

BS7002: 1989 (EN60950)

Unit in mm 10.16 0.25 +0.1 10~12 11-9A202 TOSHIBA 11-9A202

Weight: 0.44g

PIN CONFIGURATIONS (TOP VIEW)



1: ANODE 2: CATHODE

3: NC

4: TERMINAL 1 6: TERMINAL 2

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